



SANYO Semiconductors

DATA SHEET

An ON Semiconductor Company

2SA2126 — PNP Epitaxial Planar Silicon Transistor — DC / DC Converter Applications

Applications

- DC / DC converter, relay drivers, lamp drivers, motor drivers

Features

- Adoption of MBIT processes
- Low collector-to-emitter saturation voltage
- High current capacitance
- High-speed switching

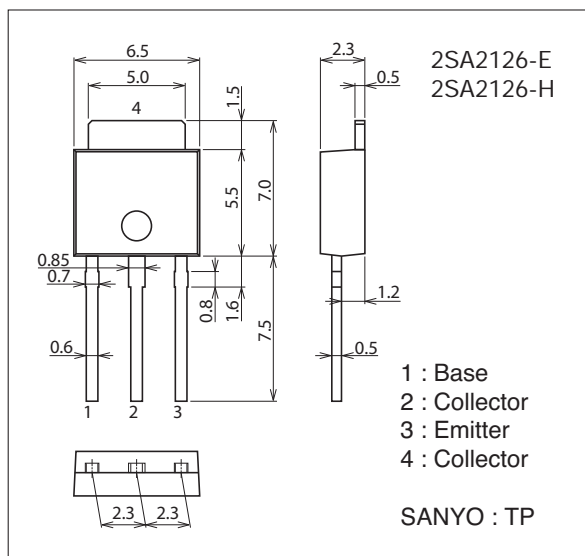
Specifications

Absolute Maximum Ratings at Ta=25°C

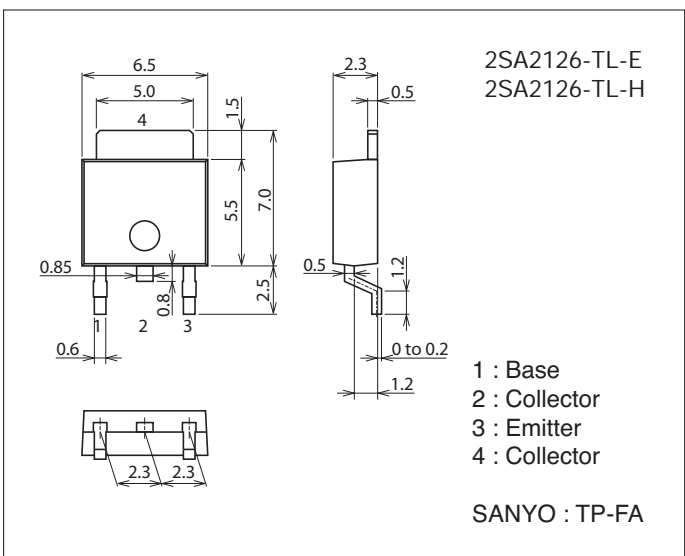
Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO		-50	V
Collector-to-Emitter Voltage	VCES		-50	V
Collector-to-Emitter Voltage	VCEO		-50	V
Emitter-to-Base Voltage	VEBO		-6	V
Collector Current	IC		-3	A
Collector Current (Pulse)	ICP		-6	A
Base Current	IB		-600	mA

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Package Dimensions unit : mm (typ)



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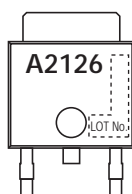


Product & Package Information

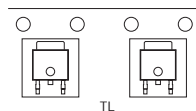
- Package : TP
- JEITA, JEDEC : SC-64, TO-251
- Minimum Packing Quantity : 500 pcs./bag

- Package : TP-FA
- JEITA, JEDEC : SC-63, TO-252
- Minimum Packing Quantity : 700 pcs./reel

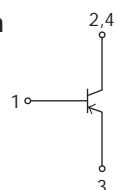
Marking (TP, TP-FA)



Packing Type (TP-FA) : TL



Electrical Connection



2SA2126

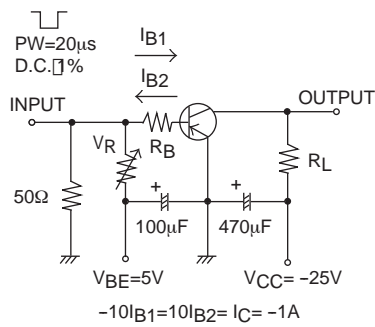
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Parameter	Symbol	Conditions	Ratings	Unit
Collector Dissipation	PC		0.8	W
		T _c =25°C	15	W
Junction Temperature	T _j		150	°C
Storage Temperature	T _{stg}		-55 to +150	°C

Electrical Characteristics at T_a=25°C

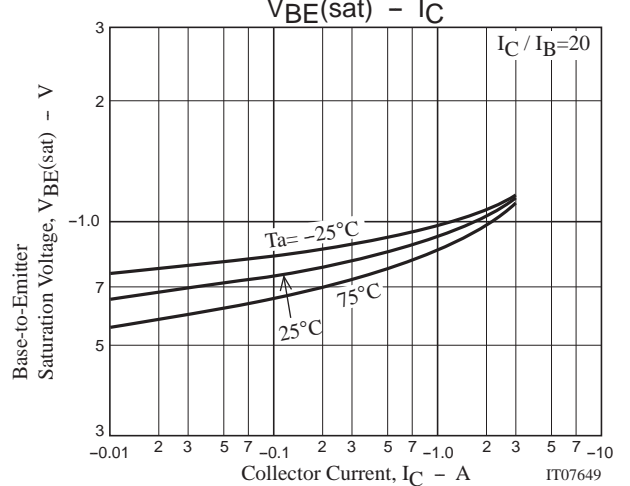
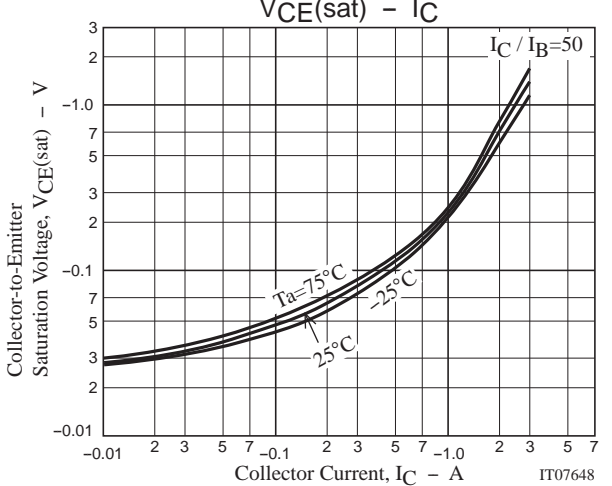
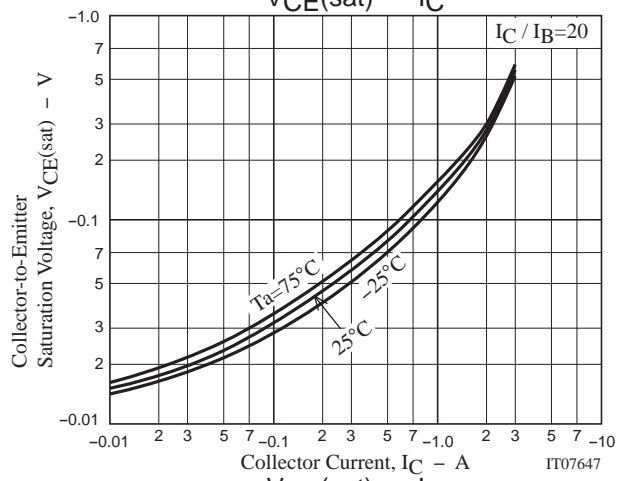
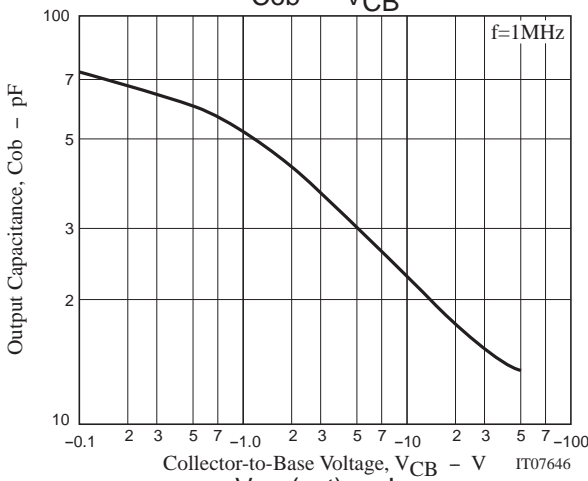
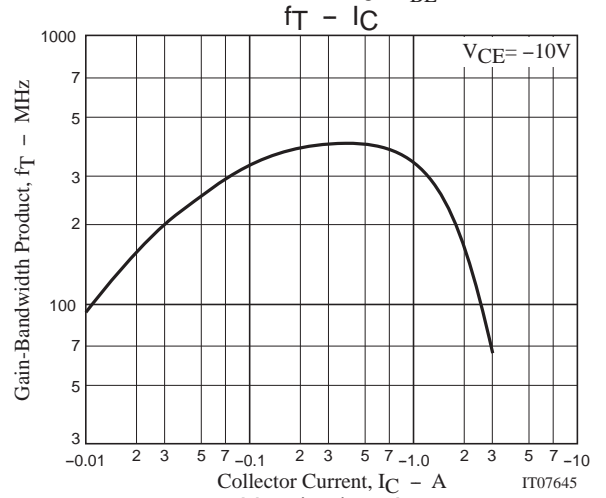
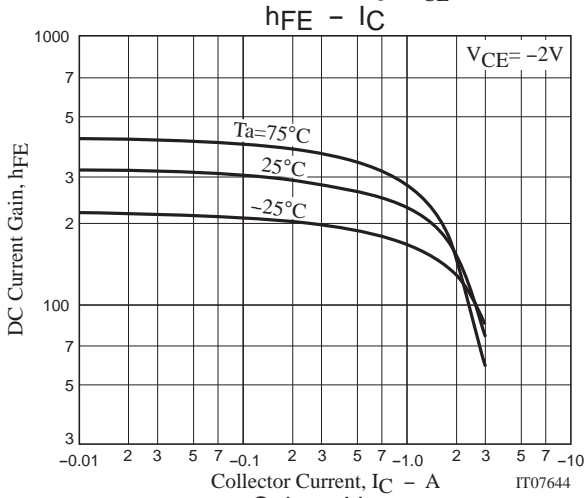
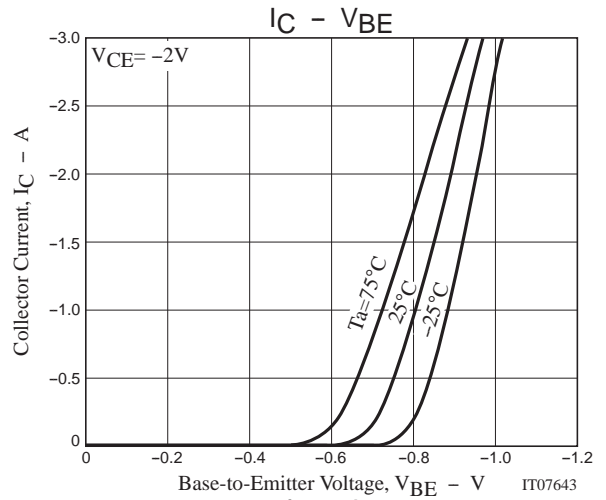
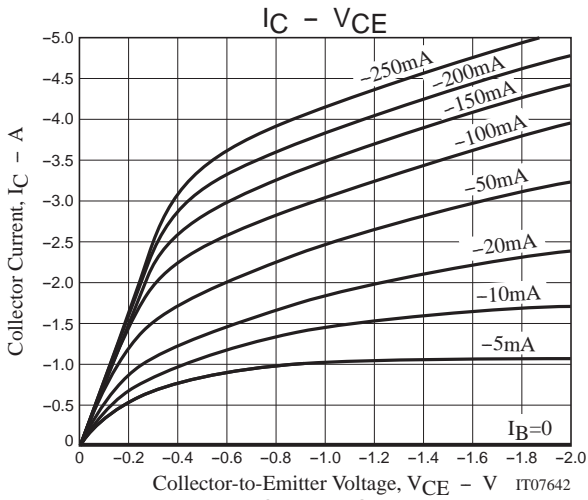
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I _{CBO}	V _{CB} = -40V, I _E = 0A			-1	μA
Emitter Cutoff Current	I _{EBO}	V _{EB} = -4V, I _C = 0A			-1	μA
DC Current Gain	h _{FE}	V _{CE} = -2V, I _C = -100mA	200		560	
Gain-Bandwidth Product	f _T	V _{CE} = -10V, I _C = -500mA		390		MHz
Output Capacitance	C _{ob}	V _{CB} = -10V, f = 1MHz		24		pF
Collector-to-Emitter Saturation Voltage	V _{CE(sat)1}	I _C = -1A, I _B = -50mA		-135	-270	mV
	V _{CE(sat)2}	I _C = -2A, I _B = -100mA		-260	-520	mV
Base-to-Emitter Saturation Voltage	V _{BE(sat)}	I _C = -2A, I _B = -100mA		-0.96	-1.2	V
Collector-to-Base Breakdown Voltage	V _{(BR)CBO}	I _C = -10μA, I _E = 0A	-50			V
Collector-to-Emitter Breakdown Voltage	V _{(BR)CES}	I _C = -100μA, R _{BE} = 0	-50			V
Collector-to-Emitter Breakdown Voltage	V _{(BR)CEO}	I _C = -1mA, R _{BE} = ∞	-50			V
Emitter-to-Base Breakdown Voltage	V _{(BR)EBO}	I _E = -10μA, I _C = 0A	-6			V
Turn-On Time	t _{on}	See specified Test Circuit.		30		ns
Storage Time	t _{stg}			230		ns
Fall Time	t _f			18		ns

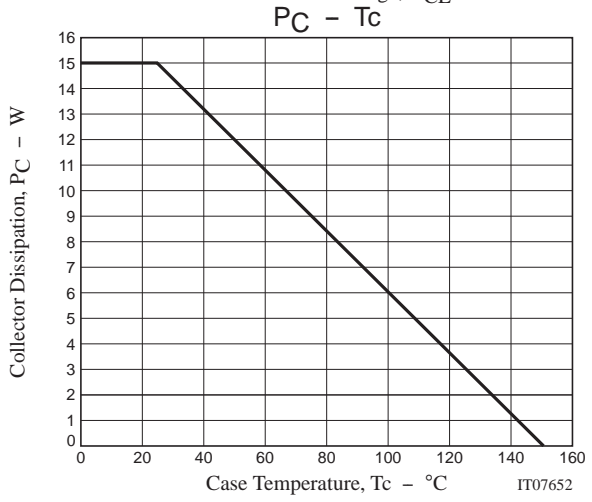
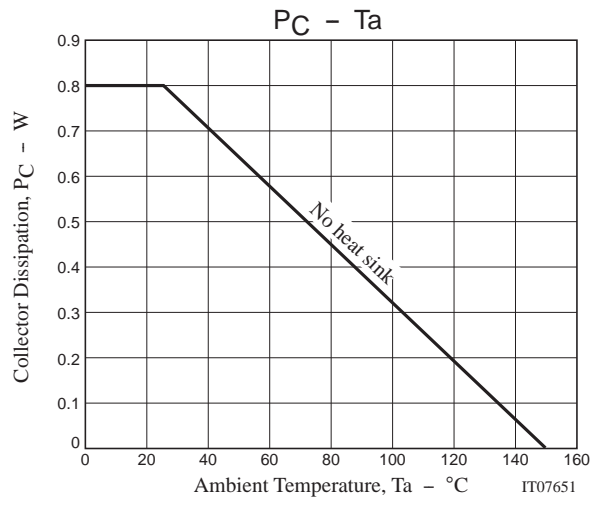
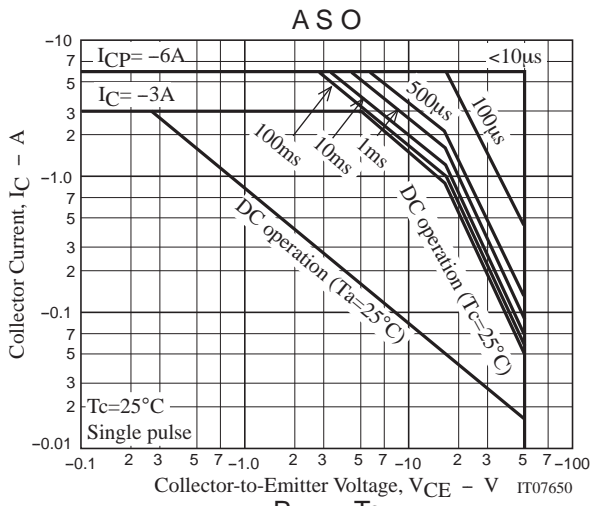
Switching Time Test Circuit



Ordering Information

Device	Package	Shipping	memo
2SA2126-E	TP	500pcs./bag	Pb Free
2SA2126-H	TP	500pcs./bag	Pb Free and Halogen Free
2SA2126-TL-E	TP-FA	700pcs./reel	Pb Free
2SA2126-TL-H	TP-FA	700pcs./reel	Pb Free and Halogen Free





Taping Specification

2SA2126-TL-E, 2SA2126-TL-H

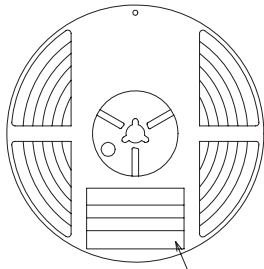
Packing Format

Package Name	Carrier Tape Type	Maximum Number of devices contained (pcs)			Packing format	
		Reel	Inner box	Outer box	Inner BOX (C-1)	Outer BOX (A-7)
TP-FA	TP	700	2,100	12,600	3 reels contained Dimensions:mm (external) 183×72×185	6 inner boxes contained Dimensions:mm (external) 440×195×210

Reel label, Inner box label
(unit:mm)

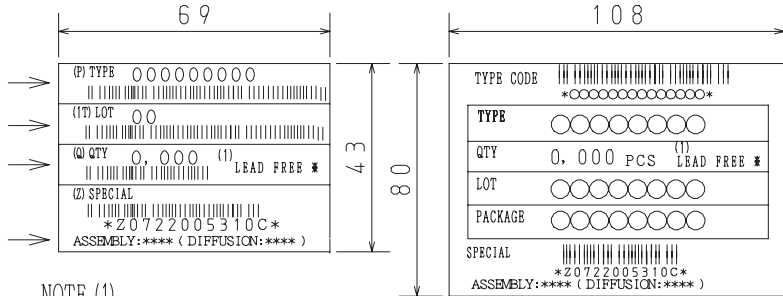
Outer box label
It is a label at the time of factory shipments.
The form of a label may change in physical distribution process.

Packing method



Type No.
LOT No.
Quantity
Origin

Reel label



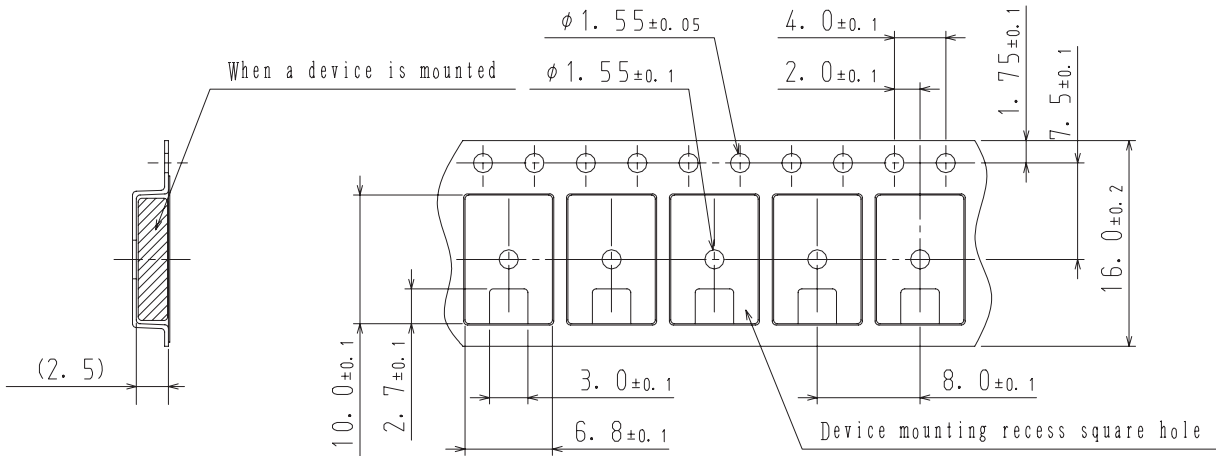
NOTE (1)

The LEAD FREE * description shows that the surface treatment of the terminal is lead free.

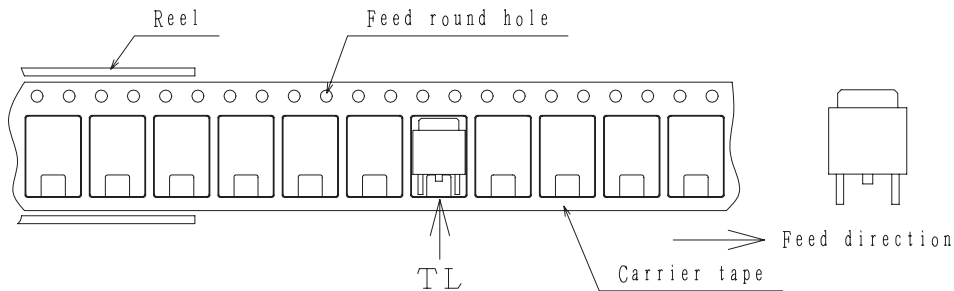
Label	JEITA Phase
LEAD FREE 3	JEITA Phase 3A
LEAD FREE 4	JEITA Phase 3

Taping configuration

1. Carrier tape size (unit:mm)



2. Device placement direction

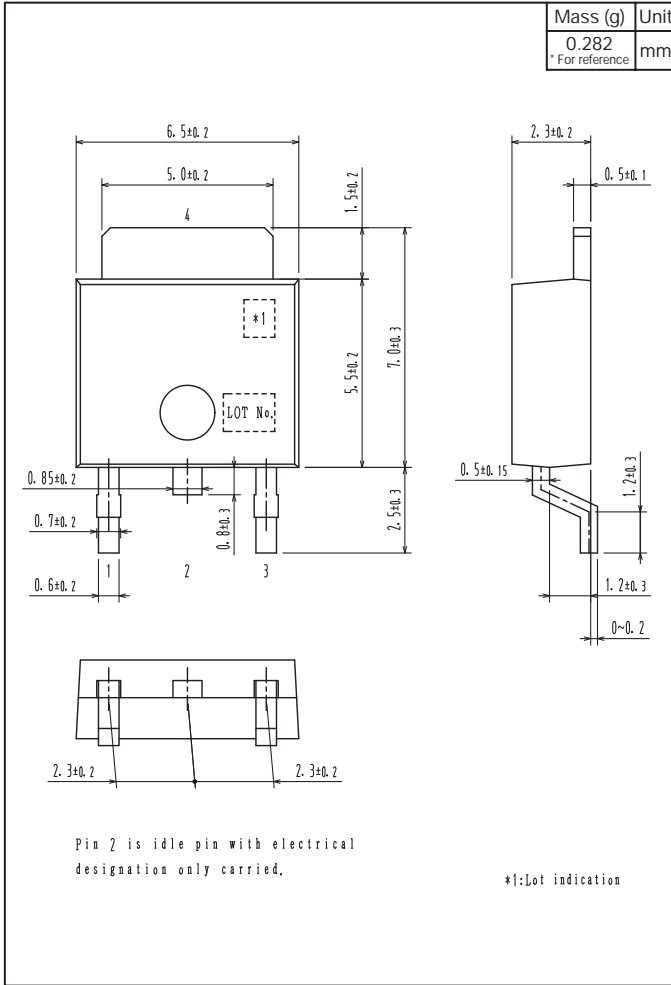


Those with one electrode terminal on the feed hole side.....TL

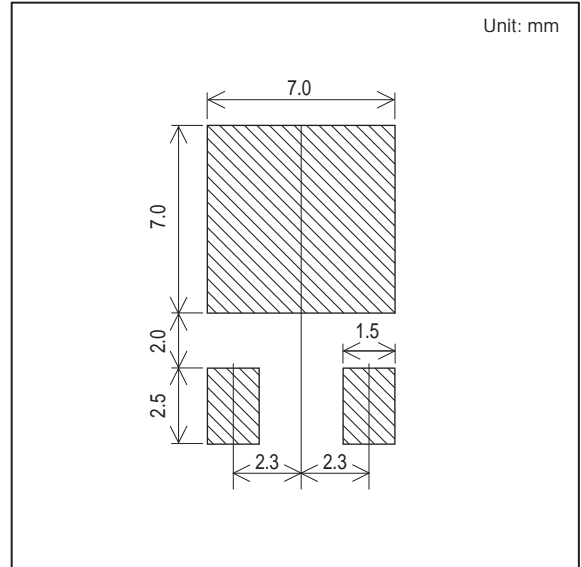
2SA2126

Outline Drawing

2SA2126-TL-E, 2SA2126-TL-H



Land Pattern Example



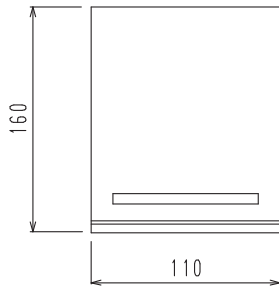
Bag Packing Specification

2SA2126-E, 2SA2126-H

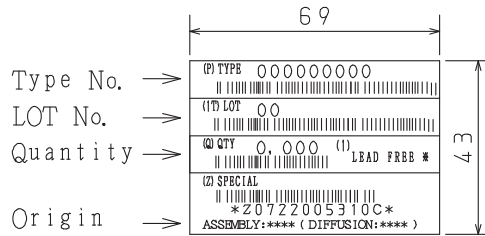
1. Packing Format

Package Name	Maximum Number of devices contained (pcs)			
	Bag	Inner box	Outer box	
TP	500	B-1	A-1	A-2
		10,000	50,000	30,000
	Packing format (Dimensions:mm (external))			
		Inner box	Outer box	
		B-1	A-1	A-2
		445×225×55	470×250×300	470×250×190

2. Bag dimensions
(unit:mm)



3. Bag label, Inner box label
(unit:mm)



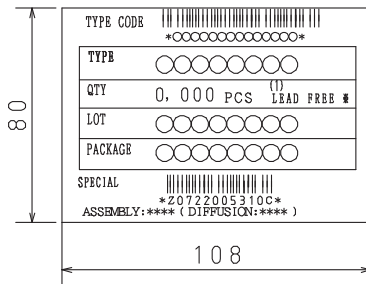
4. Outer box label
(unit:mm)

It is a label at the time of factory shipments,
The form of a label may change in physical
distribution process,

NOTE (1)

The LEAD FREE * description shows that the
surface treatment of the terminal is lead free.

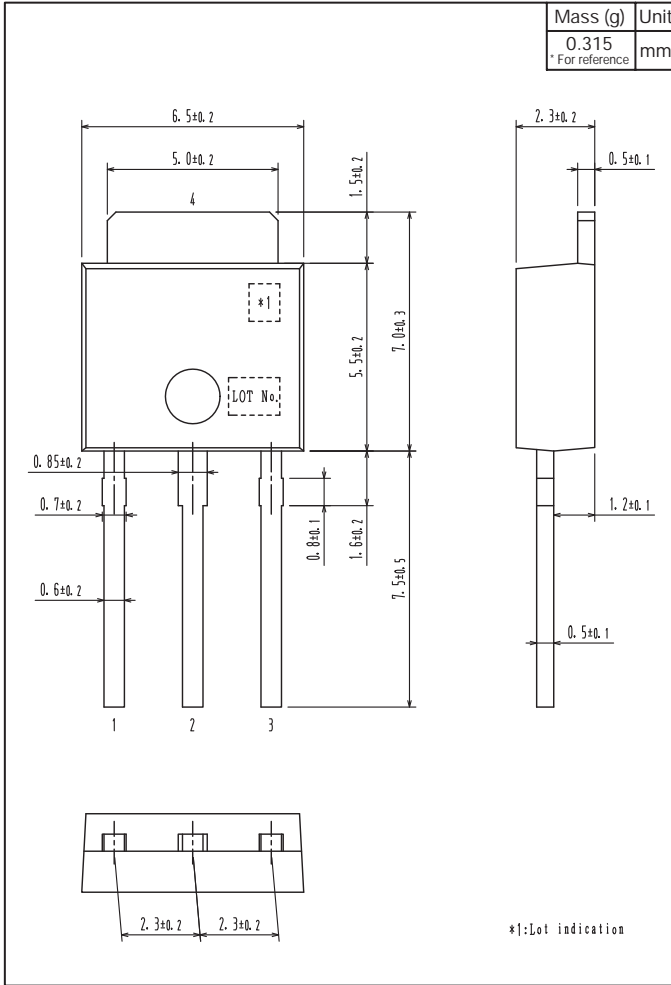
Label	JEITA Phase
LEAD FREE 3	JEITA Phase 3A
LEAD FREE 4	JEITA Phase 3



2SA2126

Outline Drawing

2SA2126-E, 2SA2126-H



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